## Size-Dependent Temperature Effects on PbSe Nanocrystals

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## **Supporting Information**

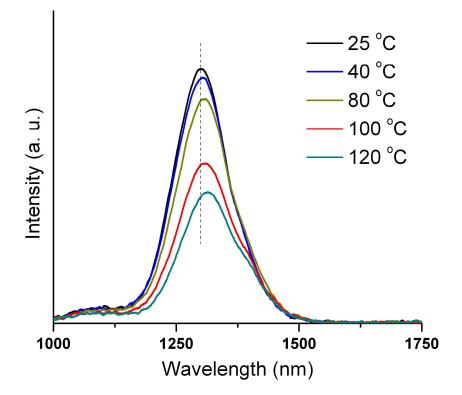
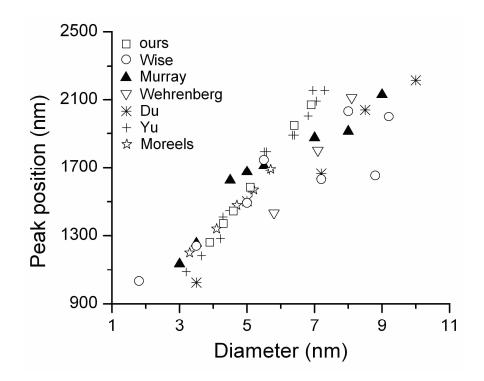
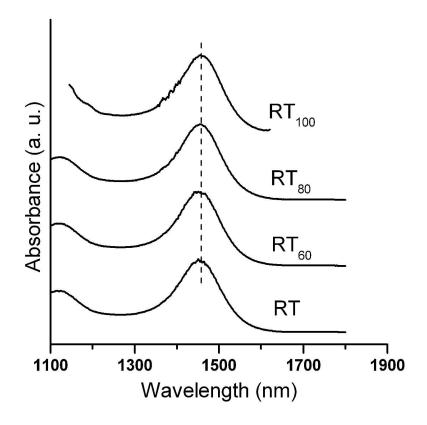


Figure S1. Temperature-induced shifts of photoluminescence spectra of the 3.9 nm PbSe nanocrystals.



**Figure S2.** First absorption peak positions versus particle sizes of the PbSe nanocrystals collected from our experiment and the literature.<sup>1-6</sup>



**Figure S3.** Room-temperature Measurements of absorption spectra of the PbSe nanocrystal sample before and after multiple heating/cooling cycles. We started the measurement of the sample at room temperature (marked as RT in the graph). Next, the sample was measured again, after being heated to 60 °C and then cooled down back to room temperature (marked as  $RT_{60}$  in the graph). Subsequently, we measured the sample for the third and fourth times, after it was respectively heated to 80 °C and 100 °C and cooled down back to room temperature (marked as  $RT_{80}$  and  $RT_{100}$  in the graph).

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